



Spec No.: DS-30-99-190 Effective Date: 04/19/2000

Revision: -

LITE-ON DCC

RELEASE

BNS-OD-FC001/A4

LITEON

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FEATURES

- *0.7 INCH (17.22mm) DIGIT HEIGHT.
- *CONTINUOUS UNIFORM SEGMENTS.
- *LOW POWER REQUIREMENT.
- *EXCELLENT CHARACTERS APPEARANCE.
- *HIGH BRIGHTNESS & HIGH CONTRAST.
- *WIDE VIEWING ANGLE.
- * SOLID STATE RELIABILITY.
- *CATEGORIZED FOR LUMINOUS INTENSITY.

DESCRIPTION

The LTP-757G-03 is a 0.7 inch (17.22 mm) matrix height 5 x 7 dot matrix displays. This device utilizes green LED chips, which are made from GaP on a non-transparent GaP substrate, and has a gray face and white dot.

DEVICE

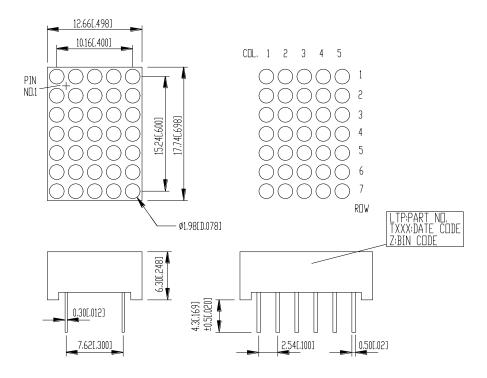
PART NO.	DESCRIPTION		
GREEN	Cathode Column		
LTP-757G-03	Anode Row		

PART NO.: LTP-757G-03 PAGE: 1 of 5

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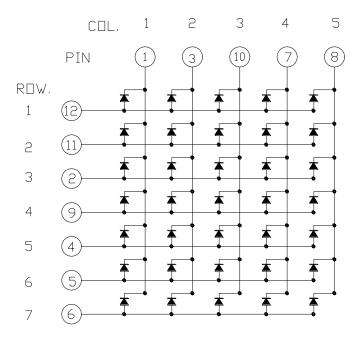
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PACKAGE DIMENSIONS



NOTES: All dimensions are in millimeters. Tolerance is \pm 0.25-mm (0.01") unless otherwise noted.

INTERNAL CIRCUIT DIAGRAM



PART NO.: LTP-757G-03 PAGE: 2 of 5

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PIN CONNECTION

No.	CONNECTION				
1	CATHODE COLUMN	1			
2	ANODE ROW 3				
3	CATHODE COLUMN	2			
4	ANODE ROW 5				
5	ANODE ROW 6				
6	ANODE ROW 7				
7	CATHODE COLUMN	4			
8	CATHODE COLUMN	5			
9	ANODE ROW 4				
10	CATHODE COLUMN	3			
11	ANODE ROW 2				
12	ANODE ROW 1				

PART NO.: LTP-757G-03 PAGE: 3 of 5



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ABSOLUTE MAXIMUM RATING AT T_A =25°C

PARAMETER	MAXIMUM RATING	UNIT			
Average Power Dissipation Per dot	36	mW			
Peak Forward Current Per dot	100	mA			
Average Forward Current Per dot	13	mA			
Derating Linear From 25 ^o C Per dot	0.17	mA/ ⁰ C			
Reverse Voltage Per dot	5	V			
Operating Temperature Range	-35^{0} C to $+85^{0}$ C				
Storage Temperature Range	-35^{0} C to $+85^{0}$ C				
Solder Temperature 1/16 inch Below Seating Plane for 3 Seconds at 260 ^o C					

ELECTRICAL / OPTICAL CHARACTERISTICS AT T_A=25°C

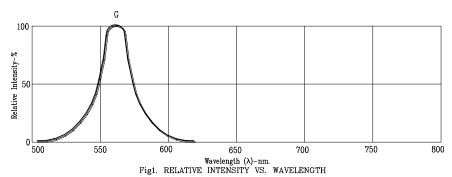
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Average Luminous Intensity	Iv	630	2000		μcd	I _P =80mA , 1/16Duty
Peak Emission Wavelength	λр		565		nm	I _F =20mA
Spectral Line Half-Width	Δλ		30		nm	I _F =20mA
Dominant Wavelength	λd		569		nm	I _F =20mA
Forward Voltage Per dot			2.1	2.6	V	I _F =20mA
	V_{F}		3.0	3.7	V	I _F =80mA
Reverse Current Per dot	IR			100	μΑ	V _R =5V
Luminous Intensity Matching Ratio	Iv-m			2:1		I _F =10mA

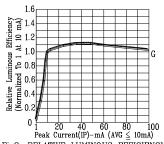
Note: Luminous intensity is measured with a light sensor and filter combination that approximates the CIE (Commision Internationale De L'Eclairage) eye-response curve.

PAGE: 4 of 5 PART NO.: LTP-757G-03

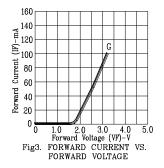
TYPICAL ELECTRICAL / OPTICAL CHARACTERISTIC CURVES

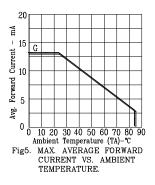
(25°C Ambient Temperature Unless Otherwise Noted)

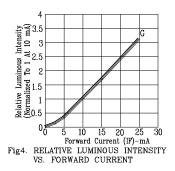


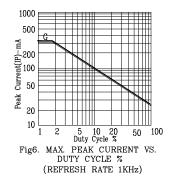


0 1 20 40 60 80 100 Peak Current(IP)-mA (AVG ≤ 10mA) RELATIVE LUMINOUS EFFICIENCY (LUMINOUS INTENSITY PER UNIT CURRENT) VS. PEAK CURRENT (REFRESH RATE 1KHZ)









NOTE: G=GREEN

PAGE: PART NO.: LTP-757G-03 5 of 5